

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	28979	SOI (silicon near on near insulator)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/09 11:00
L2	94247	MOSFET (Metal near oxide near semiconductor near field near effect near transistor) misfet	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/09 11:01
L3	694	channel with (fully near deplet\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/09 11:01
L4	350	1 and 2 and 3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/11/09 11:01